

Features

- Split Gate Trench MOSFET Technology
- Low R_{DS(on)} & FOM
- Extremely Low Switching Loss
- Excellent Stability and Uniformity
- Fast Switching and Soft Recovery
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- Moisture Sensitivity Level 1

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 15°C/W Junction to Ambient(t≤10S)⁽¹⁾
- Thermal Resistance: 60°C/W Junction to Ambient(Steady-State)⁽¹⁾
- Thermal Resistance: 0.35°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	180	А
Pulsed Drain Current ⁽²⁾	I _{DM}	540	Α
Total Power Dissipation ⁽³⁾	P _D	357	W
Single Pulsed Avalanche Energy ⁽⁴⁾	E _{AS}	1568	mJ

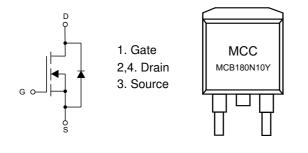
Note:

1. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^{\circ}$ C. The Power dissipation PDSM is based on $R_{\theta JA}$ t \leq 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.

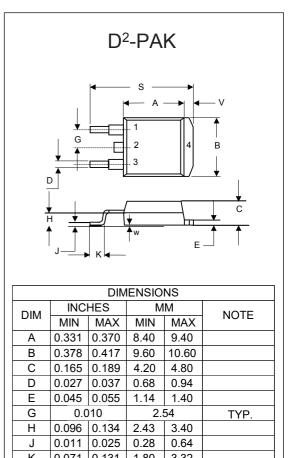
2. Repetitive rating; pulse width limited by max. junction temperature.

- 3. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 4. V_{DD} =50V, R_{G} =25 Ω , L=2mH, I_{AS} =56A.

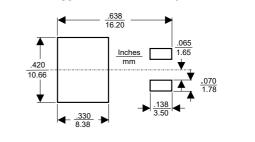
Internal Structure and Marking Code



N-CHANNEL MOSFET



n	0.071	0.131	1.80	3.3Z			
S	0.575	0.625	14.60	15.87			
V	0.042	0.058	1.07	1.47			
W	0.000	0.010	0.00	0.25			
Suggested Solder Pad Layout							





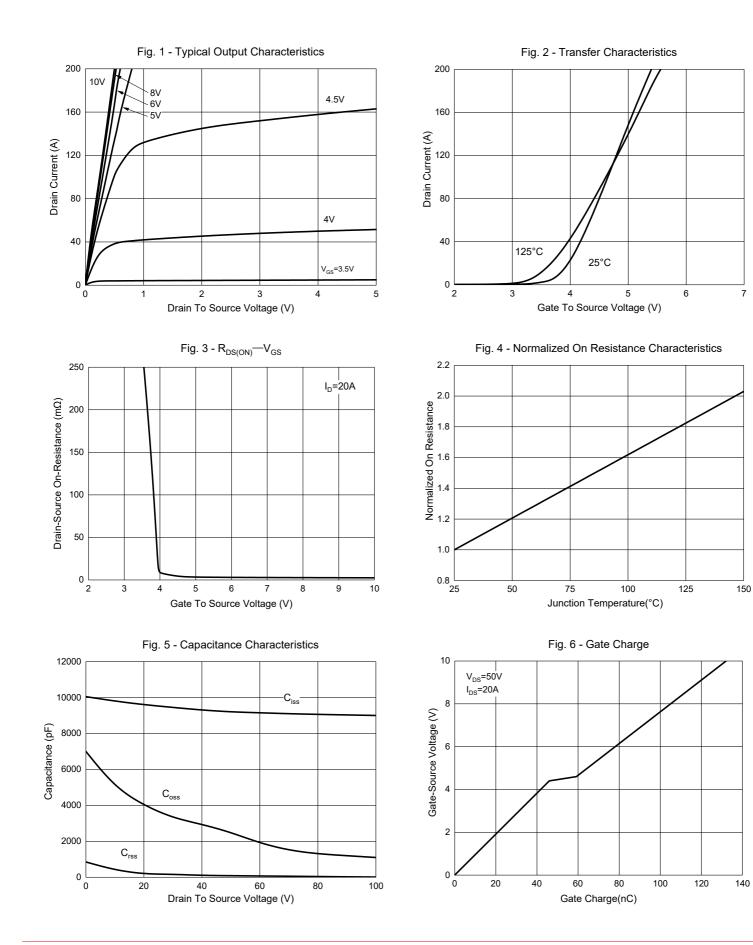
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics				1	1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} =0V, I _D =250 μ A	100			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	2.8	4	V	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		2.7	3.3	mΩ	
Gate Resistance	R _g	f=1MHz, Open drain		0.8		Ω	
Diode Characteristics							
Continuous Body Diode Current	I _S				180	A	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.3	V	
Reverse Recovery Time	t _{rr}	I _s =20A,di/dt=100A/µs		81.9		ns	
Reverse Recovery Charge	Q _{rr}	1 ₅ -20A,01/01-100A/µ5		186		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			9200			
Output Capacitance	C _{oss}	V_{DS} =50V, V_{GS} =0V,f=1MHz		2500		pF	
Reverse Transfer Capacitance	C _{rss}			86		1	
Total Gate Charge	Qg			132			
Gate-Source Charge	Q _{gs}	V_{DS} =50V, V_{GS} =10V, I_{D} =20A		46		nC	
Gate-Drain Charge	Q _{gd}			13.2			
Turn-On Delay Time	t _{d(on)}			22.9			
Turn-On Rise Time	t _r	V _{DD} =50V, V _{GS} =10V,		39.3		ne	
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =2.2 Ω , I_D =20A		43.7		ns	
Turn-Off Fall Time	t _f			51.5			





Curve Characteristics





Curve Characteristics

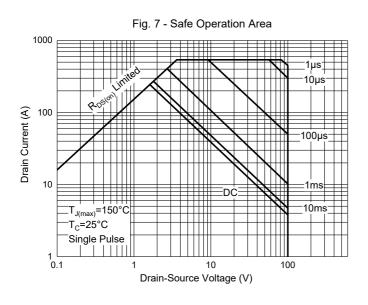
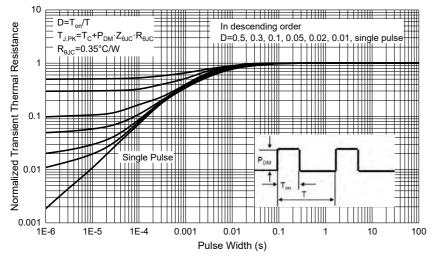


Fig. 8 - Normalized Maximum Transient Thermal Impedance





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 800pcs/Reel	

Note : Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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